TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7PA17FU

Dual Schmitt Buffer

Features

- Operating voltage range: V_{CC} = 1.8 to 3.6 V
- High-speed operation: t_{pd} = 4.0 ns (max) at V_{CC} = 3.0 to 3.6 V

 t_{pd} = 4.3 ns (max) at V_{CC} = 2.3 to 2.7 V

 t_{pd} = 8.6 ns (max) at V_{CC} = 1.8 V

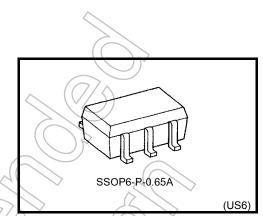
• High-level output current:

 I_{OH}/I_{OL} = ±24 mA (min) at V_{CC} = 3.0 V

 I_{OH}/I_{OL} = ±18 mA (min) at V_{CC} = 2.3 V

 $I_{OH}/I_{OL} = \pm 6$ mA (min) at $V_{CC} = 1.8$ V

- 3.6-V tolerant inputs.
- 3.6-V power down protection outputs

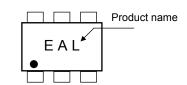


Weight: 0.0068 g (typ.)

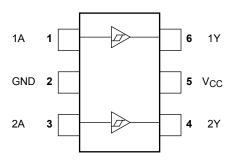
Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage	Vcc	-0.5 to 4.6	V	
DC input voltage	VIN	-0.5 to 4.6	7\v	
DC output voltage	(7/	-0.5 to 4.6 (Note 1)) v	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 2)	, v	
Input diode current		-50	mA	
Output diode current	lok	-50 (Note 3)	mA	
DC output current	OUT	±50	mA	
Power dissipation	PD	200	mW	
DC V _{CC} /ground current	Icc	±100	mA	
Storage temperature	T _{stg}	-65 to 150	°C	

Marking



Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{CC} = 0 V$

Note 2: High or Low State. IOUT absolute maximum rating must be observed.

Note 3: V_{OUT} < GND

Start of commercial production 2002-12

IEC Logic Symbol



Truth Table

Α	Y
L	L
Н	Н

Operating Ranges

Characteristics	Symbol	Rating	(Unit)
Supply voltage	V _{CC}	1.8 to 3.6	V
Supply voltage	VCC.	1.2 to 3.6 (Note 4)	
Input voltage	V _{IN}	-0.3 to 3.6	V
Output voltage	V _{OUT}	0 to 3.6 (Note 5)	V
Output voltage		0 to V _{CC} (Note 6)	,
		±24 (Note 7)	\Diamond
Output Current	I _{OH} /I _{OL}	±18 (Note 8)	mA
		±6 (Note 9)	(0)
Operating temperature	T _{opr}	-40 to 85	°C)

Note 4: Data retention only

Note 5: $V_{CC} = 0 V$

Note 6: High or Low state

Note 7: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 8: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$

Note 9: $V_{CC} = 1.8 \text{ V}$

Electrical Characteristics

DC Characteristics (2.7 V < V_{CC} \le 3.6 V)

Characteristics		Symbol	Symbol Test Condition		Test Condition		to 85°C	Unit
Characteris	1105	Symbol	V _{CC} (V)	Min			Max	Offic
High level Threshold Voltage		V _P		3.6	_	2.2	V	
		VΡ			3.0	_	2.0	V
Tilleshold Vollage	Low level	V _N			3.6	0.8		٧
	LOW level	۷N		_	3.0	0.7	_	V
Hysteresis Voltage		V _H			3.6	0.3	1.2	V
Trysteresis voltage		۷ П	_		3.0	0.3	1.2	V
Hig				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_	
	High level	V _{OH}	$V_{IN} = V_{IH}$	I _{OH} = -12 mA	2.7	22	\rightarrow	
				lон = −18 mA	3.0	2.4	> —	
Output Voltage				I _{OH} = -24 mA	3.0	2.2	_	V
		Low level V _{OL}	$I_{OL} = 100 \mu A$		2.7 to 3.6	4	0.2	
	Low level		V _{IN} = V _{IL}	I _{OL} = 12 mA	2.7	>_	0.4	
	2011 10101	*OL	VIII VIII	I _{OL} = 18 mA	3.0	—	0.4	
				I _{OL} = 24 mA	3.0	—	0.55	
Input Leakage Current		I _{IN}	$V_{IN} = 0 \text{ to } 3.6 \text{ V}$		2.7 to 3.6	_	±5.0	μΑ
Power-off Leakage Curr	rent	loff	V_{IN} , $V_{OUT} = 0$ to	3.6 V	0	_	10.0	μΑ
Quiescent Supply Current		Icc	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	20.0	
			$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		2.7 to 3.6	_	±20.0	μА
Increase in I _{CC} per Inpu	ut	Atcc	V _{IH} = V _{CC} − 0.6 (<u> </u>	2.7 to 3.6	_	750	

DC Characteristics (2.3 V ≤ V_{CC} ≤ 2.7 V)

Characteristics		Symbol Test Condition			Ta = 40	to 85°C	Unit				
Charac	teristics	Symbol	Test C	orialilori	V _{CC} (V)	Min	Max	Offic			
Threshold Voltage	High level	V _P		_	2.3	_	1.8	V			
Tillesiloid Voltage	Low level	V _N		_	2.3	0.5	_	V			
Hysteresis Voltage		VH		_	2.3	0.3	1.0	V			
))	V _O H		$I_{OH} = -100 \mu A$	2.3 to 2.7	V _{CC} - 0.2					
	High level		VOH	VOH	V _{OH} V _{IN} = V _{IH}	V _{IN} = V _{IH}	$I_{OH} = -6 \text{ mA}$	2.3	2.0	_	
				$I_{OH} = -12 \text{ mA}$	2.3	1.8	_				
Output Voltage				I _{OH} = -18 mA	2.3	1.7	_	V			
				I _{OL} = 100 μA	2.3 to 2.7	_	0.2				
	Low level	V _{OL}	$V_{IN} = V_{IL}$	I _{OL} = 12 mA	2.3	_	0.4				
				I _{OL} = 18 mA	2.3	_	0.6				
Input Leakage Curr	rent	I _{IN}	V _{IN} = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μΑ			
Power-off Leakage	Current	loff	V_{IN} , $V_{OUT} = 0$ to	3.6 V	0	_	10.0	μΑ			
Quiescent Supply Current		loo	V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0	^			
Quiescent Supply (Juli elit	Icc	V _{CC} ≤ (V _{IN} , V _{OU}	r) ≤ 3.6 V	2.3 to 2.7	_	±20.0	μА			

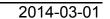
DC Characteristics (1.8 V \leq V_{CC} < 2.3 V)

Characteristics		Cymbol	Test Condition			Ta = 40 to 85°C		Unit
Charac	tenstics	Symbol	Symbol Test Condition		V _{CC} (V)	Min	Max	Oill
Threshold Voltage	High level	V _P	-	_	1.8	_	1.4	V
Threshold Voltage	Low level	V _N	-	_	1.8	0.25		V
Hysteresis Voltage		V _H	-	_	1.8	0.2	0.95	٧
	High level V _{OH}	V _{IN} = V _{IH}	I _{OH} = -100 μA	1.8	V _{CC} + 0.2	_		
Output Voltage			I _{OH} = -6 mA	1,8	1.4		V	
,	Low level	Va	V _{IN} = V _{II}	I _{OL} = 100 μA	1.8	_	0.2	
	Low level	V _{OL}	VIN = VIL	I _{OL} = 6 mA	1.8	_	0.3	
Input Leakage Curr	rent	I _{IN}	V _{IN} = 0 to 3.6 V		1.8	_	±5.0	μА
Power-off Leakage	Current	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	\supset	10.0	μА
Quiescent Supply Current			V _{IN} = V _{CC} or GND		1.8		20.0	μА
Quiescent Supply C	Junent	Icc	V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V	1.8	2	±20.0	μΑ

AC Characteristics (Input $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500~\Omega$)

Characteristics	Cymbal	Test Condition		Ta = 40 t	o 85°C	Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)	Min	Max	Offic
	. <		1.8	1.0	8.6	
Propagation delay time	t _{pLH}	(Figure 1 and 2)	2.5 ± 0.2	0.8	4.3	ns
	t _{pHL}		3.3 ± 0.3	0.6	4.0	

For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.



Dynamic Switching Characteristics (Input $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

Characteristics	Cumbal	Toot Co		Ta = 25°C	Unit	
Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур	Utill
		V _{IN} = 1.8 V, V _{IL} = 0 V	(Note 10)	1.8	0.25	
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 10)	2.5	0.6	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 10)	3.3	0.8	
		$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 10)	1.8	-0.25	
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	V _{IN} = 2.5 V, V _{IL} = 0 V	(Note 10)	2.5	-0.6	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 10)	3.3	-0.8	
		V _{IN} = 1.8 V, V _{IL} = 0 V	(Note 10)	1.8	1.5	
Quiet Output Minimum Dynamic V _{OH}	V _{OLP}	$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 10)	2.5	1.9	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note 10)	3.3	2.2	

Note 10: Characteristics guaranteed by design.

Capacitive Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C	Unit
Characteristics	Symbol	rest condition	Vcc (V)	Тур	Offic
Input Capacitance	C _{IN}		1.8, 2.5, 3.3	4	pF
Power Dissipation Capacitance	C_{PD}	f _{IN} = 10 MHz (Not	e 11) 1.8, 2.5, 3.3	27	pF

Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

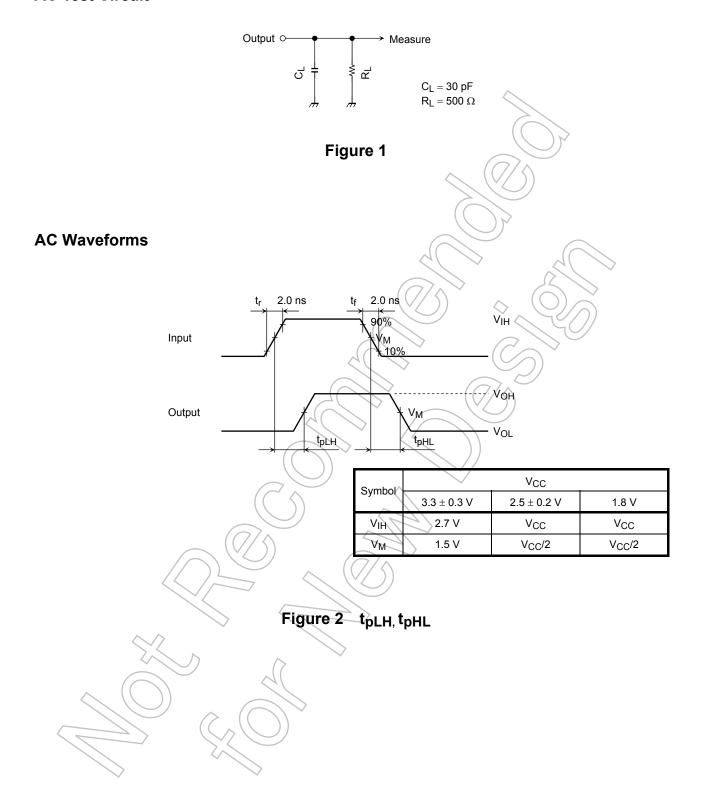
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Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

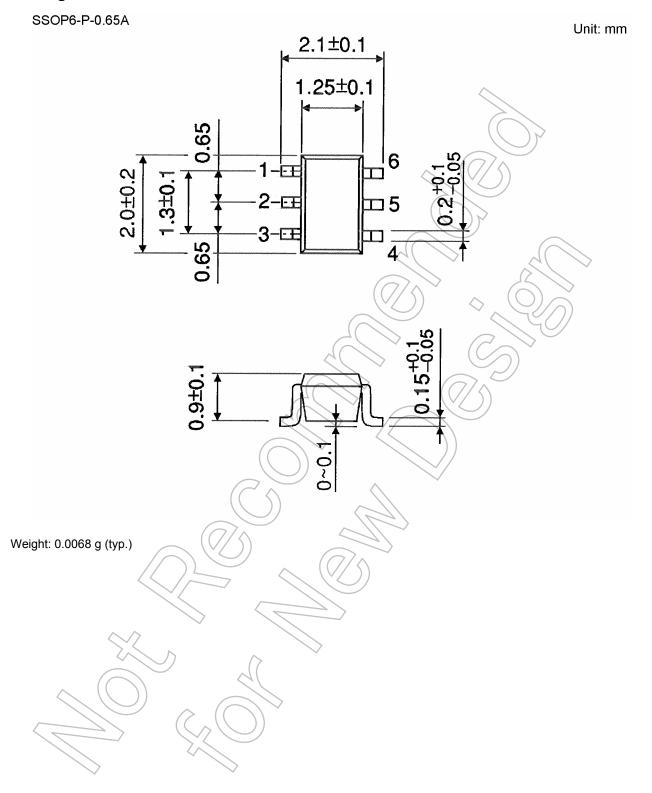
2014-03-01

AC Test Circuit



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Package Dimensions



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